WHAT IS CLAIMED IS:

ı	I. A method for determining whether a MEMS device is in a select state		
2	defined by a position of a moveable element comprised by the MEMS device, the method		
3	comprising:		
4	changing a voltage of a first region of a sensing configuration; and		
5	measuring a second region of the sensing configuration,		
6	wherein the first and second electrically active regions are electrically coupled		
7	when the MEMS device is in the select state and electrically uncoupled when the MEMS		
8	device is not in the select state.		
1	2. The method recited in claim 1 wherein the sensing configuration		
2	comprises a transistor.		
1	3. The method recited in claim 2 wherein the sensing configuration		
2	comprises a field-effect transistor having a source region corresponding to the first region and		
3	a drain region corresponding to the second region.		
1	4. The method recited in claim 2 wherein the sensing configuration		
2	comprises a bipolar junction transistor having an emitter region corresponding to the first		
3	region and a collector region corresponding to the second region.		
1	5. The method recited in claim 1 wherein:		
2	the first and second regions comprise first and second waveguide ports; and		
3	measuring the second region comprises measuring an impedance between the		
4	first and second waveguide ports.		
1	6. The method recited in claim 1 wherein the moveable element is not in		
2	contact with the first or second, regions when in the position defining the select state.		
1	7. The method recited in claim 1 wherein the moveable element is in		
2	contact with the first and second regions when in the position defining the select state.		
Į	8. The method recited in claim 7 wherein the first and second regions		
2	comprise electrically conductive regions.		

9.

16.

comprise first and second waveguide ports.

1 2 the voltage and measuring the second region periodically.

1

The method recited in claim 1 further comprising performing changing

The method recited in claim 12 wherein the first and second regions

1	17. The method recited in claim 12 wherein the moveable element is in		
2	contact with the first and second regions when in the position.		
1	18. The MEMS device recited in claim 12 further comprising a dynamic		
2	refresh driver electrically coupled with the first region and configured to periodically provid		
3	an ac signal to the first region.		
1	19. A microstructure for steering light, the microstructure comprising:		
1	a substrate;		
2			
3	a structural linkage connected with the substrate and supporting a moveable		
4	element disposed to orient a reflective coating;		
5	an electrode disposed to provide an electrostatic force on the moveable		
6	element upon actuation; and		
7	a sensing configuration having first and second regions that are electrically		
8	coupled only when the moveable element is in a position that defines a select state for the		
9	microstructure.		
	20 Miles in the second of the		
l	20. The microstructure recited in claim 19 wherein the sensing		
2	configuration comprises a transistor formed within the substrate.		
1	21. The microstructure recited in claim 20 wherein:		
2	the sensing configuration comprises a field-effect transistor;		
3	the first region comprises a source of the field-effect transistor; and		
4	the second region comprises a drain of the field-effect transistor.		
1	22. The microstructure recited in claim 20 wherein:		
2	the sensing configuration comprises a bipolar junction transistor;		
3	the first region comprises an emitter of the bipolar junction transistor; and		
	the first region comprises an emitter of the bipolar junction transistor.		
4	the second region comprises a concetor of the orporar junction transistor.		
1	23. The microstructure recited in claim 19 wherein the first and second		
2	regions comprise first and second waveguide ports.		
1	24. The microstructure recited in claim 19 wherein the moveable element		
2	is in contact with the first and second regions when in the position.		
4	is in contact with the first and second regions when in the position.		

by a wavelength router.

1	25.	The microstructure recited in claim 19 wherein the microstructure is		
2	one of a plurality of similar microstructures comprised by an array.			
1	26.	The microstructure recited in claim 25 wherein:		
2	the first region of each of the microstructures is electrically coupled with a			
3	dynamic refresh driver;			
4	the e	lectrode of each of the microstructures is electrically coupled with the		
5	dynamic refresh driver; and			
6	the se	econd regions of the microstructures are electrically coupled with one		
7	another.			
1	27	The microstructure recited in claim 26 wherein the array is comprise		